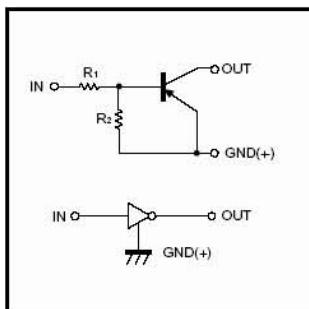


RoHS Compliant Product
A suffix of "-C" specifies halogen & lead-free

FEATURES

- Built-in bias resistors enable the configuration of an inverter circuit without connecting input resistors (see equivalent circuit).
- Only the on/off conditions need to be set for operation, making device design easy.
- The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.

EQUIVALENT CIRCUIT



DTA114YE (SOT-523)	DTA114YUA (SOT-323)
Φ: In Ω: Gnd Ω: Out	Φ: In Ω: Gnd Ω: Out
DTA114YSA (TO-92S)	DTA114YCA (SOT-23)
Φ: In Ω: Out Ω: Gnd	Φ: In Ω: Gnd Ω: Out

ABSOLUTE MAXIMUM RATINGS at Ta = 25°C

Parameter	Symbol	Ratings				Unit
		E	UA	CA	SA	
Supply voltage	V _{CC}			-50		V
Input voltage	V _{IN}		-40 ~ +6			V
Output current	I _O		-70			mA
	I _{CMAX}		-100			
Power dissipation	P _C	150		200	300	mW
Junction & Storage temperature	T _J , T _{STG}		150, -55~150			°C

ABSOLUTE MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS at Ta = 25°C

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Input voltage	V _{II(OFF)}	-	-	-0.3	V	V _{CC} =-5V, I _O =-100μA
	V _{II(ON)}	-1.4	-	-		V _O =-0.3V, I _O =-1mA
Output voltage	V _{O(ON)}	-	-	-0.3	V	I _O /I _I =-5mA/-0.25mA
Input current	I _I	-	-	-0.88	mA	V _I =5V
Output current	I _{OFF}	-	-	-0.5	μA	V _{CC} =-50V, V _I =0
DC current gain	G _I	68	-	-		V _O =-5V, I _O =-5mA
Input resistance	R _I	7	10	13	KΩ	
Resistance ratio	R ₂ / R ₁	3.7	4.7	5.7		
Transition frequency	f _T	-	250	-	MHz	V _O =-10V, I _O =5mA, f=100MHz

CHARACTERISTIC CURVES

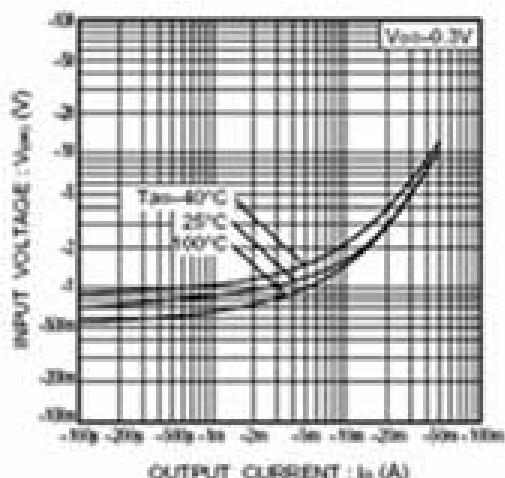


Fig.1 Input voltage vs. output current
(ON characteristics)

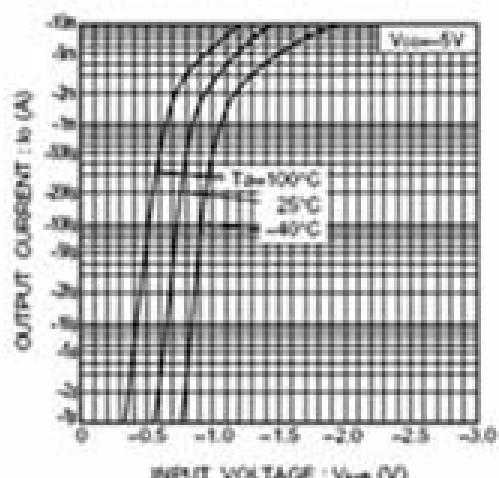


Fig.2 Output current vs. input voltage
(OFF characteristics)

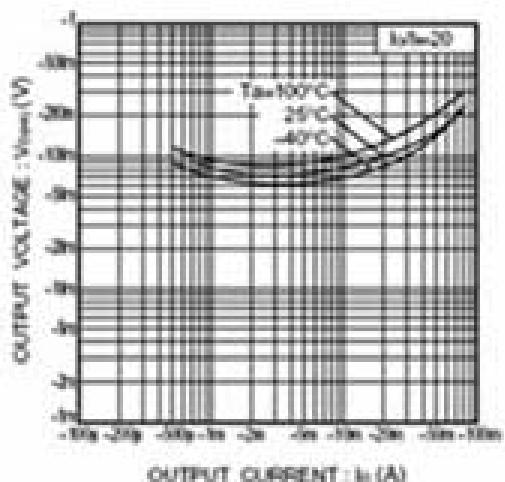


Fig.4 Output voltage vs. output current

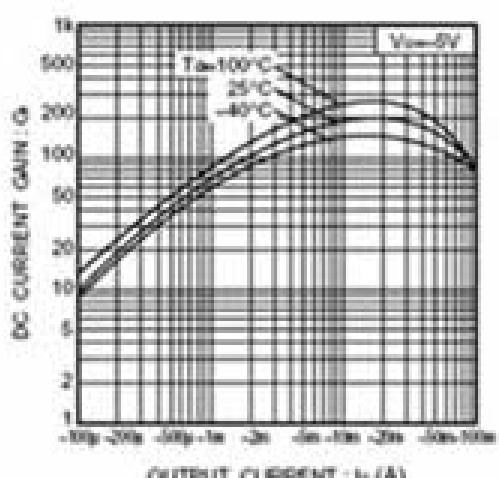


Fig.3 DC current gain vs. output current